

# 1:10 LOW JITTER UNIVERSAL BUFFER/LEVEL TRANSLATOR WITH 2:1 INPUT MUX

## Features

- 10 differential or 20 LVC MOS outputs
- Ultra-low additive jitter: 100 fs rms
- Wide frequency range: 1 to 725 MHz
- Any-format input with pin selectable output formats: LVPECL, Low Power LVPECL, LVDS, CML, HCSL, LVC MOS
- 2:1 mux with hot-swappable inputs
- Glitchless input clock switching
- Synchronous output enable
- Output clock division: /1, /2, /4
- Low output-output skew: <50 ps
- Low propagation delay variation: <400 ps
- Independent V<sub>DD</sub> and V<sub>DDO</sub>: 1.8/2.5/3.3 V
- Excellent power supply noise rejection (PSRR)
- Selectable LVC MOS drive strength to tailor jitter and EMI performance
- Small size: 44-QFN (7 mm x 7 mm)
- RoHS compliant, Pb-free
- Industrial temperature range: -40 to +85 °C



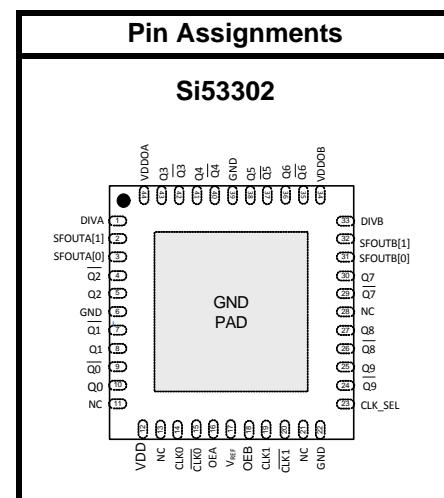
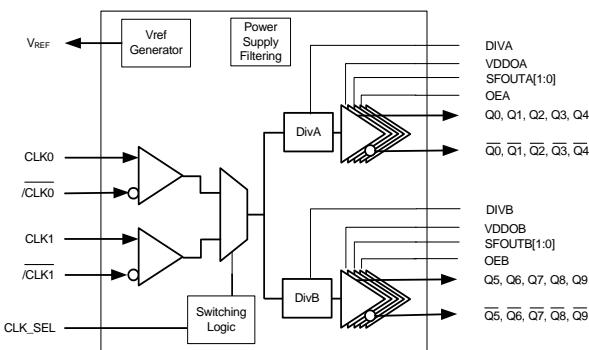
## Applications

- High-speed clock distribution
- Ethernet switch/router
- Optical Transport Network (OTN)
- SONET/SDH
- PCI Express Gen 1/2/3
- Storage
- Telecom
- Industrial
- Servers
- Backplane clock distribution

## Description

The Si53302 is an ultra low jitter ten output differential buffer with pin-selectable output clock signal format and divider selection. The Si53302 features a 2:1 mux with glitchless switching, making it ideal for redundant clocking applications. The Si53302 utilizes Silicon Laboratories' advanced CMOS technology to fanout clocks from 1 to 725 MHz with guaranteed low additive jitter, low skew, and low propagation delay variability. The Si53302 features minimal cross-talk and provides superior supply noise rejection, simplifying low jitter clock distribution in noisy environments. Independent core and output bank supply pins provide integrated level translation without the need for external circuitry.

## Functional Block Diagram



Patents pending

## TABLE OF CONTENTS

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<b>Section</b>	<b>Page</b>
<b>1. Electrical Specifications</b> .....	<b>3</b>
<b>2. Functional Description</b> .....	<b>10</b>
2.1. Universal, Any-Format Input .....	10
2.2. Input Bias Resistors .....	12
2.3. Universal, Any-Format Output Buffer .....	12
2.4. Glitchless Clock Input Switching .....	13
2.5. Synchronous Output Enable .....	13
2.6. Flexible Output Divider .....	14
2.7. Input Mux and Output Enable Logic .....	14
2.8. Power Supply ( $V_{DD}$ and $V_{DDOX}$ ) .....	14
2.9. Output Clock Termination Options .....	15
2.10. AC Timing Waveforms .....	18
2.11. Typical Phase Noise Performance .....	19
2.12. Input Mux Noise Isolation .....	20
2.13. Power Supply Noise Rejection .....	21
<b>3. Pin Description: 44-Pin QFN</b> .....	<b>22</b>
<b>4. Ordering Guide</b> .....	<b>25</b>
<b>5. Package Outline</b> .....	<b>26</b>
5.1. 7x7 mm 44-QFN Package Diagram .....	26
<b>6. PCB Land Pattern</b> .....	<b>28</b>
6.1. 7x7 mm 44-QFN Package Land Pattern .....	28
<b>7. Top Marking</b> .....	<b>29</b>
7.1. Si53302 Top Marking .....	29
7.2. Top Marking Explanation .....	29
<b>Document Change List</b> .....	<b>30</b>
<b>Contact Information</b> .....	<b>32</b>

## 1. Electrical Specifications

**Table 1. Recommended Operating Conditions**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Ambient Operating Temperature	T <sub>A</sub>		-40	—	85	°C
Supply Voltage Range*	V <sub>DD</sub>	LVDS, CML, HCSL, LVCMOS	1.71	1.8	1.89	V
		LVPECL, low power LVPECL, LVDS, CML, HCSL, LVCMOS	2.38	2.5	2.63	V
			2.97	3.3	3.63	V
Output Buffer Supply Voltage*	V <sub>DDO</sub>	LVDS, CML, HCSL, LVCMOS	1.71	—	1.89	V
		LVPECL, low power LVPECL, LVDS, CML, HCSL, LVCMOS	2.38	—	2.63	V
			2.97	—	3.63	V

\*Note: Core supply VDD and output buffer supplies V<sub>DDO</sub> are independent.

**Table 2. Input Clock Specifications**

(V<sub>DD</sub>=1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub>=-40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Differential Input Common Mode Voltage	V <sub>CM</sub>	VDD=2.5V± 5%, 3.3V± 10%	0.05	—	—	V
Input Swing (single-ended, peak-to-peak)	V <sub>IN</sub>		0.1	—	1.1	V
Input Voltage High	V <sub>IH</sub>		VDD x 0.7	—	—	V
Input Voltage Low	V <sub>IL</sub>		—	—	VDD x 0.3	V
Input Capacitance	C <sub>IN</sub>		—	5	—	pF

# Si53302

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**Table 3. DC Common Characteristics**

( $V_{DD} = 1.8 \text{ V} \pm 5\%$ ,  $2.5 \text{ V} \pm 5\%$ , or  $3.3 \text{ V} \pm 10\%$ ,  $T_A = -40$  to  $85^\circ\text{C}$ )

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Supply Current	$I_{DD}$		—	TBD	100	mA
Output Buffer Supply Current (Per Clock Output) @100 MHz	$I_{DDOX}$	LVPECL (3.3 V)	—	35	—	mA
		Low Power LVPECL (3.3 V)	—	30	—	mA
		LVDS (3.3 V)	—	20	—	mA
		CML (3.3 V)	—	30	—	mA
		HCSL, 100 MHz, 2 pF load (3.3 V)	—	35	—	mA
		CMOS (1.8 V, SFOUT = Open/0), per output, $C_L = 5 \text{ pF}$ , 200 MHz	—	5	—	mA
		CMOS (2.5 V, SFOUT = Open/0), per output, $C_L = 5 \text{ pF}$ , 200 MHz	—	8	—	mA
		CMOS (3.3V, SFOUT=0/1), per output, $C_L = 5 \text{ pF}$ , 200 MHz	—	15	—	mA
Leakage Current	$I_L$	Input leakage at all inputs except CLKIN, $V_{IN} = 0 \text{ V}$	—	—	TBD	$\mu\text{A}$
		Input leakage at CLKIN $V_{IN} = 0 \text{ V}$	—	—	TBD	$\mu\text{A}$
Voltage Reference	$V_{REF}$	$V_{REF}$ pin	—	$V_{DD}/2$	—	V
Input High Voltage	$V_{IH}$	SFOUTX, DIVX 3-level input pins	$0.85 \times V_{DD}$	—	—	V
Input Mid Voltage	$V_{IM}$	SFOUTX, DIVX 3-level input pins	$0.45 \times V_{DD}$	$0.5 \times V_{DD}$	$0.55 \times V_{DD}$	V
Input Low Voltage	$V_{IL}$	SFOUTX, DIVXpin 3-level input pins	—	—	$0.15 \times V_{DD}$	V
Internal Pull-down Resistor	$R_{DOWN}$	CLK_SEL, DIVA, DIVB, SFOUTA[1], SFOUTB[1]	—	25	—	$\text{k}\Omega$
Internal Pull-up Resistor	$R_{UP}$	SFOUTA[1], SFOUTB[1], DIVA, DIVB, OEA, OEB	—	25	—	$\text{k}\Omega$

**Table 4. DC Characteristics—LVPECL and Low Power LVPECL**(V<sub>DD</sub> = 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub> = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Voltage High	V <sub>OH</sub>	R <sub>L</sub> = 50 Ω to V <sub>DDOX</sub> –2V	V <sub>DDOX</sub> – 1.145	—	V <sub>DDOX</sub> – 0.895	V
Output Voltage Low	V <sub>OL</sub>	R <sub>L</sub> = 50 Ω to V <sub>DDOX</sub> –2V	V <sub>DDOX</sub> – 1.945	—	V <sub>DDOX</sub> – 1.695	V
Output DC Common Mode Voltage	V <sub>COM</sub>		V <sub>DDOX</sub> – 1.895	—	V <sub>DDOX</sub> – 1.425	V
Single-Ended Output Swing	V <sub>SE</sub>	Terminate unused outputs to R <sub>L</sub> = 50 Ω to V <sub>DDOX</sub> –2 V	0.25	0.60	0.85	V

**Table 5. DC Characteristics—CML**(V<sub>DD</sub> = 1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub> = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Single-Ended Output Swing	V <sub>SE</sub>	Terminated as shown in Figure 8 (CML termination).	300	400	500	mV

**Table 6. DC Characteristics—LVDS**(V<sub>DD</sub> = 1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub> = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Single-Ended Output Swing	V <sub>SE</sub>	R <sub>L</sub> = 100 Ω across Q <sub>N</sub> and $\bar{Q}_N$	247	—	454	mV
Output Common Mode Voltage (V <sub>DDO</sub> =2.5V or 3.3V)	V <sub>COM1</sub>	V <sub>DDOX</sub> = 2.38 to 2.63 V, 2.97 to 3.63 V, R <sub>L</sub> = 100 Ω across Q <sub>N</sub> and $\bar{Q}_N$	1.10	1.25	1.35	V
Output Common Mode Voltage (V <sub>DDO</sub> =1.8V)	V <sub>COM2</sub>	V <sub>DDOX</sub> = 1.71 to 1.89 V, R <sub>L</sub> = 100 Ω across Q <sub>N</sub> and $\bar{Q}_N$	0.85	0.97	1.10	V

# Si53302

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**Table 7. DC Characteristics—LVC MOS**(V<sub>DD</sub> = 1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub> = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Voltage High*	V <sub>OH</sub>		0.85 x V <sub>DDOX</sub>	—	—	V
Output Voltage Low*	V <sub>OL</sub>		—	—	0.15 x V <sub>DDOX</sub>	V

\*Note: I<sub>OH</sub> and I<sub>OL</sub> per the Output Signal Format Table for specific V<sub>DDOX</sub> and SFOUTX settings.

**Table 8. DC Characteristics—HCSL**(V<sub>DD</sub> = 1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub> = –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Output Voltage High	V <sub>OH</sub>	R <sub>L</sub> = 50 Ω to GND	550	700	850	mV
Output Voltage Low	V <sub>OL</sub>	R <sub>L</sub> = 50 Ω to GND	–150	0	150	mV
Single-Ended Output Swing	V <sub>SE</sub>	R <sub>L</sub> = 50 Ω to GND	—	700	—	mV
Crossing Voltage	V <sub>C</sub>	R <sub>L</sub> = 50 Ω to GND	250	350	550	mV

**Table 9. AC Characteristics**(V<sub>DD</sub> = 1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%, T<sub>A</sub> = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency	F	LVPECL, low power LVPECL, LVDS, CML, HCSL	1	—	725	MHz
		LVCMOS	1	—	200	MHz
Duty Cycle <b>Note:</b> 50% input duty cycle.	D <sub>C</sub>	200 MHz, 50 Ω to V <sub>DD</sub> /2, 20/80% T <sub>R</sub> /T <sub>F</sub> <10% of period (LVCMOS)	TBD	TBD	TBD	%
		20/80% T <sub>R</sub> /T <sub>F</sub> <10% of period (Differential)	48	50	52	%
Minimum Input Clock Slew Rate <sup>1</sup>	SR	Required to meet prop delay and additive jitter specifications (20-80%)	0.75	—	—	V/ns
Output Rise/Fall Time	T <sub>R</sub> /T <sub>F</sub>	LVPECL, LVDS, CML, HCSL, 20/80%			350	ps
		200 MHz, 50 Ω, 20/80%, 2 pF load (LVCMOS)	TBD	TBD	750	ps
Minimum Input Pulse Width	T <sub>W</sub>		500	—	—	ps
Additive Jitter (Differential Clock Input)	J	V <sub>DD</sub> = 2.5/3.3 V, LVPECL/LVDS, F = 725 MHz, 0.75 V/ns input slew rate	—	60	80	fs
Propagation Delay	T <sub>PLH</sub> , T <sub>PHL</sub>	Low to high, high to low Single-ended	TBD	—	TBD	ns
		Low to high, high to low Differential	TBD	—	TBD	ns
Output Enable Time <sup>2</sup>	T <sub>EN</sub>	F = 1 MHz	—	2	—	μs
		F = 100 MHz	—	60	—	ns
		F = 725 MHz	—	50	—	ns
Output Disable Time <sup>2</sup>	T <sub>DIS</sub>	F = 1 MHz	—	2	—	μs
		F = 100 MHz	—	25	—	ns
		F = 725 MHz	—	15	—	ns

**Notes:**

- 1. For clock division applications, a minimum input clock slew rate of 30 mV/ns is required.
- 2. See Figure 4.
- 3. Defined as skew between outputs on different devices operating at the same supply voltages, temperatures, and equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.
- 4. Measured for 156.25 MHz carrier frequency. Sine-wave noise added to V<sub>DDOX</sub> (1.8 V = 50 mV<sub>PP</sub>, 2.5/3.3 V = 100 mV<sub>PP</sub>) and noise spur amplitude measured. See AN491 for further details.

# Si53302

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**Table 9. AC Characteristics (Continued)**

( $V_{DD} = 1.8 \text{ V} \pm 5\%$ ,  $2.5 \text{ V} \pm 5\%$ , or  $3.3 \text{ V} \pm 10\%$ ,  $T_A = -40 \text{ to } 85^\circ\text{C}$ )

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit	
Output to Output Skew	$T_{SK}$	Identical Configuration, Single-ended ( $Q_N$ to $Q_M$ )	—	—	100	ps	
		Identical Configuration, Differential ( $Q_N$ to $Q_M$ )	—	—	50	ps	
Part to Part Skew <sup>3</sup>	$T_{PS}$	Identical configuration	—	50	—	ps	
Power Supply Noise Rejection <sup>4</sup>	PSRR	10 kHz sinusoidal noise	—	-90	—	dBc	
		100 kHz sinusoidal noise	—	-90	—	dBc	
		500 kHz sinusoidal noise	—	-80	—	dBc	
		1 MHz sinusoidal noise	—	-70	—	dBc	
<b>Notes:</b>							
1. For clock division applications, a minimum input clock slew rate of 30 mV/ns is required.							
2. See Figure 4.							
3. Defined as skew between outputs on different devices operating at the same supply voltages, temperatures, and equal load conditions. Using the same type of inputs on each device, the outputs are measured at the differential cross points.							
4. Measured for 156.25 MHz carrier frequency. Sine-wave noise added to $V_{DDOX}$ ( $1.8 \text{ V} = 50 \text{ mV}_{PP}$ , $2.5/3.3 \text{ V} = 100 \text{ mV}_{PP}$ ) and noise spur amplitude measured. See AN491 for further details.							

**Table 10. Thermal Conditions**

Parameter	Symbol	Test Condition	Value	Unit
Thermal Resistance, Junction to Ambient	$\theta_{JA}$	Still air	46.2	°C/W
Thermal Resistance, Junction to Case	$\theta_{JC}$	Still air	27.1	°C/W

**Table 11. Absolute Maximum Ratings**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Storage Temperature	$T_S$		-55	—	150	°C
Supply Voltage	VDD		-0.5	—	3.8	V
Input Voltage	$V_{IN}$		-0.5	—	VDD+ 0.3	V
Output Voltage	$V_{OUT}$		—	—	VDD+ 0.3	V
ESD Sensitivity	HBM	HBM, 100 pF, 1.5 kΩ	2000	—	—	V
ESD Sensitivity	CDM		500	—	—	V
Peak Soldering Reflow Temperature	$T_{PEAK}$	Pb-Free; Solder reflow profile per JEDEC J-STD-020	—	—	260	°C
Maximum Junction Temperature	$T_J$		—	—	125	°C

**Note:** Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.

## 2. Functional Description

The Si53302 is a low jitter, low skew 1:10 differential buffer with an integrated 2:1 input mux. The device has a universal input that accepts most common differential or LVCMOS input signals. A clock select pin is used to select the active input clock. The selected clock input is routed to two independent banks of outputs. Each output bank features control pins to select signal format, output enable, output divider setting and LVCMOS drive strength.

### 2.1. Universal, Any-Format Input

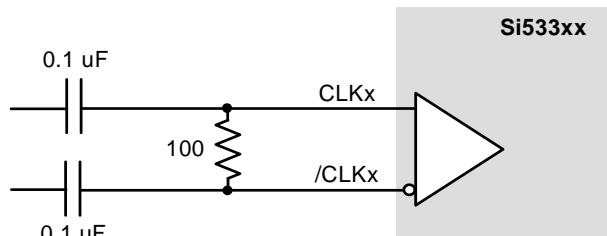
The Si53302 has a universal input stage that enables simple interfacing to a wide variety of clock formats, including LVPECL, LVCMOS, LVDS, HCSL, and CML. Tables 12 and 13 summarize the various input ac- and dc-coupling options supported by the device. Figures 3 and 4 show the recommended input clock termination options.

**Table 12. LVPECL, LVCMOS, and LVDS**

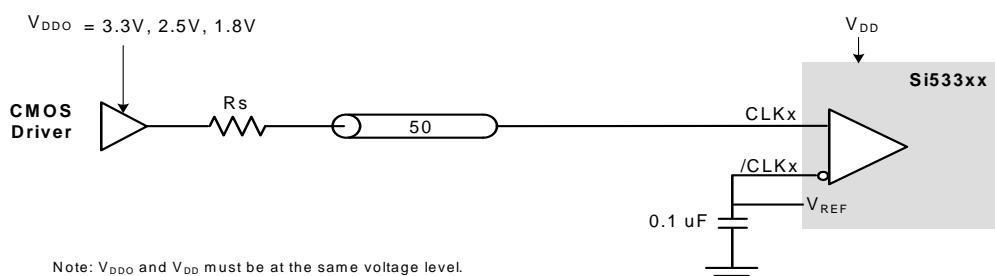
LVPECL		LVCMOS		LVDS	
AC-Couple	DC-Couple	AC-Couple	DC-Couple	AC-Couple	DC-Couple
1.8 V	N/A	N/A	No	Yes	Yes
2.5/3.3 V	Yes	Yes	No	Yes	Yes

**Table 13. HCSL and CML**

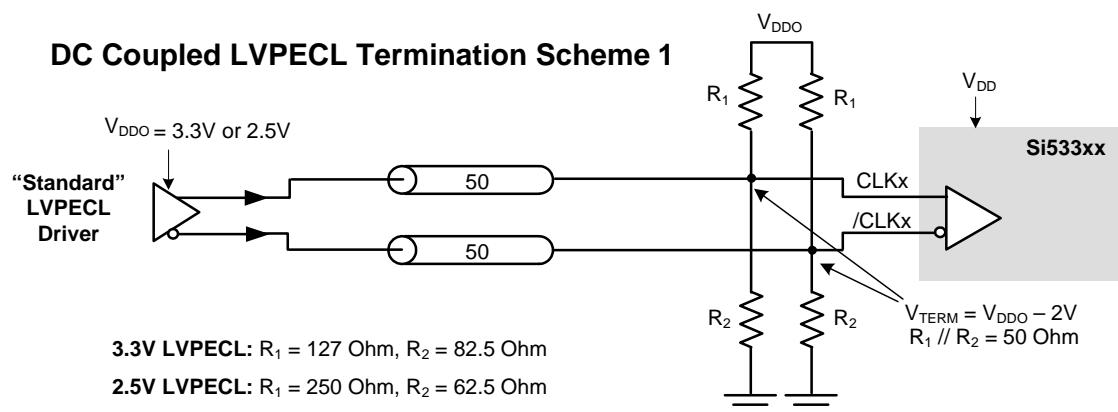
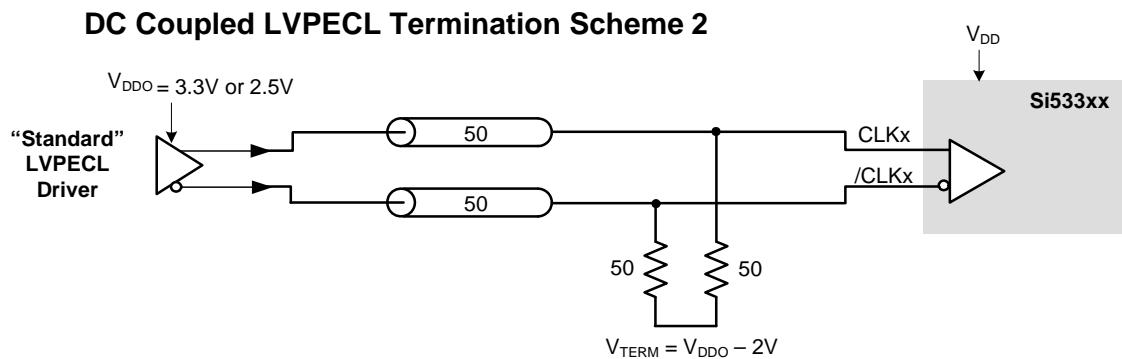
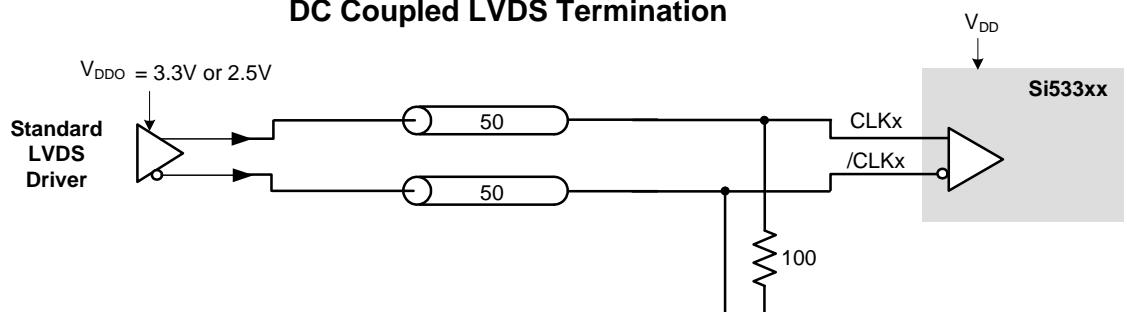
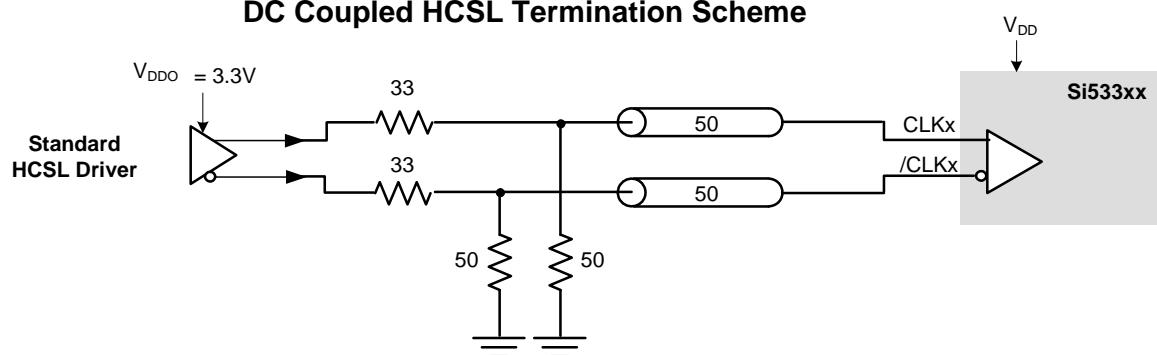
HCSL		CML	
AC-Couple	DC-Couple	AC-Couple	DC-Couple
1.8 V	No	No	Yes
2.5/3.3 V	No	Yes (3.3 V)	Yes



**Figure 1. Differential LVPECL, LVDS, CML AC-Coupled Input Termination**



**Figure 2. LVCMOS DC-Coupled Input Termination**

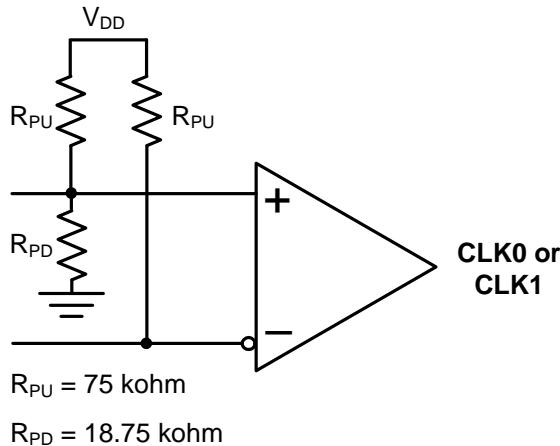
**DC Coupled LVPECL Termination Scheme 1****DC Coupled LVPECL Termination Scheme 2****DC Coupled LVDS Termination****DC Coupled HCSL Termination Scheme**

Note: 33 Ohm series termination is optional depending on the location of the receiver.

**Figure 3. Differential DC-Coupled Input Terminations**

## 2.2. Input Bias Resistors

Internal bias resistors ensure a differential output low condition in the event that the clock inputs are not connected. The noninverting input is biased with a 18.75 k $\Omega$  pulldown to GND and a 75 k $\Omega$  pullup to V<sub>DD</sub>. The inverting input is biased with a 75 k $\Omega$  pullup to V<sub>DD</sub>.



**Figure 4. Input Bias Resistors**

## 2.3. Universal, Any-Format Output Buffer

The Si53302 has highly flexible output drivers that support a wide range of clock signal formats, including LVPECL, low power LVPECL, LVDS, CML, HCSL, and LVC MOS. SFOUTA[1] and SFOUTB[1] are 3-level inputs that can be pin-strapped to select the Bank A and Bank B clock signal formats, respectively. This feature enables the device to be used for level translation in addition to clock distribution, minimizing the number of unique buffer part numbers required in a typical application and simplifying design reuse. For EMI reduction applications, four LVC MOS drive strength options are available for each V<sub>DDO</sub> setting.

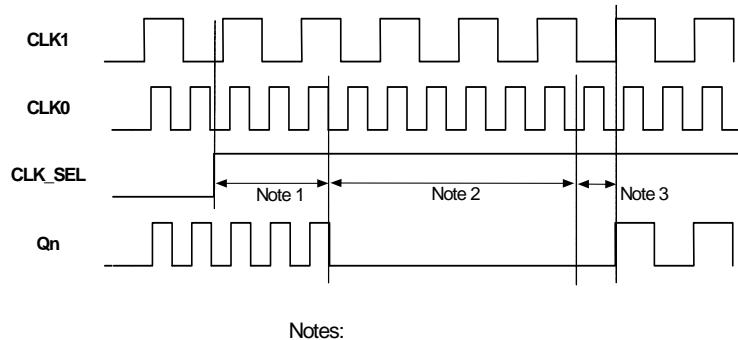
**Table 14. Output Signal Format Selection**

SFOUTX[1]	SFOUTX[0]	V <sub>DDOX</sub> = 3.3 V	V <sub>DDOX</sub> = 2.5 V	V <sub>DDOX</sub> = 1.8 V
Open*	Open*	LVPECL	LVPECL	N/A
0	0	LVDS	LVDS	LVDS
0	1	LVC MOS, 24mA drive	LVC MOS, 18mA drive	LVC MOS, 12mA drive
1	0	LVC MOS, 18mA drive	LVC MOS, 12mA drive	LVC MOS, 9mA drive
1	1	LVC MOS, 12mA drive	LVC MOS, 9mA drive	LVC MOS, 6mA drive
Open*	0	LVC MOS, 6mA drive	LVC MOS, 4mA drive	LVC MOS, 2mA drive
Open*	1	LVPECL Low power	LVPECL Low power	N/A
0	Open*	CML	CML	CML
1	Open*	HCSL	HCSL	HCSL

**Note:** SFOUTX[1:0] are 3-level input pins. Tie low for "0" setting. Tie high for "1" setting. When left open, the pin floats to V<sub>DD</sub>/2.

## 2.4. Glitchless Clock Input Switching

The Si53302 features glitchless switching between two valid input clocks. Figure 5 illustrates that switching between input clocks does not generate runt pulses or glitches at the output.



Notes:

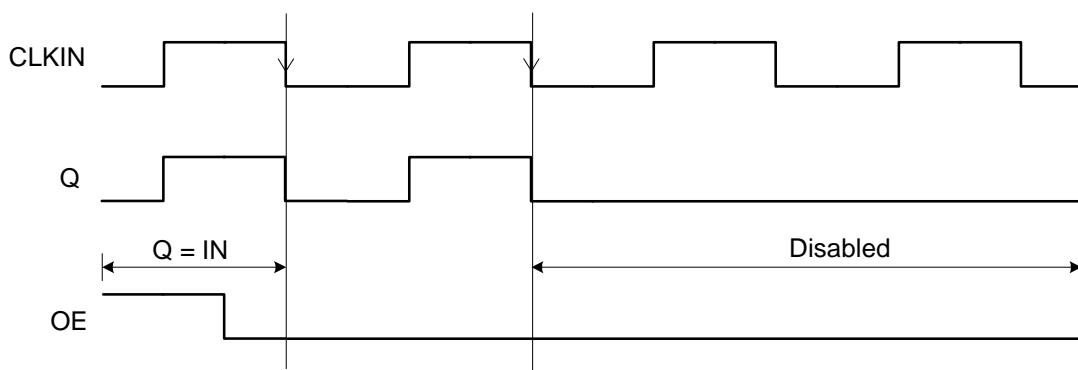
1.  $Q_n$  continues with CLK0 for 2-3 falling edges of CLK0.
2.  $Q_n$  is disabled low for 2-3 falling edges of CLK1.
3.  $Q_n$  starts on the first rising edge after 1 + 2.

**Figure 5. Glitchless Input Clock Switch**

The Si53302 supports glitchless switching between clocks at the same frequency. In addition, the device supports glitchless switching between 2 input clocks that are up to 10x different in frequency. When a switchover to a new clock is made, the output will disable low after two or three clock cycles of the previously-selected input clock. The outputs will remain low for up to three clock cycles of the newly-selected clock, after which the outputs will start from the newly-selected input. In the case a switchover to an absent clock is made, the output will glitchlessly stop low and wait for edges of the newly selected clock. A switchover from an absent clock to a live clock will also be glitchless. Note that the CLK\_SEL input should not be toggled faster than 1/250th the frequency of the slower input clock.

## 2.5. Synchronous Output Enable

The Si53302 features a synchronous output enable (disable) feature. Output enable is sampled and synchronized on the falling edge of the input clock. This feature prevents runt pulses from being generated when the outputs are enabled or disabled.



Note 1. Outputs are disabled after 1 to 2 negative edges of the input clock.

**Figure 6. Synchronous Output Enable**

When OE is low,  $Q$  is held low and  $\bar{Q}$  is held high for differential output formats. For LVCMOS output format options, both  $Q$  and  $\bar{Q}$  are held low when OE is set low. The device outputs are enabled when the output enable pin is unconnected.

## 2.6. Flexible Output Divider

The Si53302 provides optional clock division in addition to clock distribution. The divider setting for each bank of output clocks is selected via 3-level control pins as shown in the table below. Leaving the DIVX pins open will force a divider value of 1 which is the default mode of operation.

**Table 15. Divider Selection**

DIVX	Divider Value
Open*	÷1 (default)
0	÷2
1	÷4

\*Note: DIVX are 3-level input pins. Tie low for "0" setting. Tie high for "1" setting. When left open, the pin floats to  $V_{DD}/2$ .

## 2.7. Input Mux and Output Enable Logic

The Si53302 provides two clock inputs for applications that need to select between one of two clock sources. The CLK\_SEL pin selects the active clock input. The table below summarizes the input and output clock based on the input mux and output enable pin settings.

**Table 16. Input Mux and Output Enable Logic**

CLK_SEL	CLK0	CLK1	OE <sup>1</sup>	Q <sup>2</sup>
L	L	X	H	L
L	H	X	H	H
H	X	L	H	L
H	X	H	H	H
X	X	X	L	L <sup>3</sup>

**Notes:**

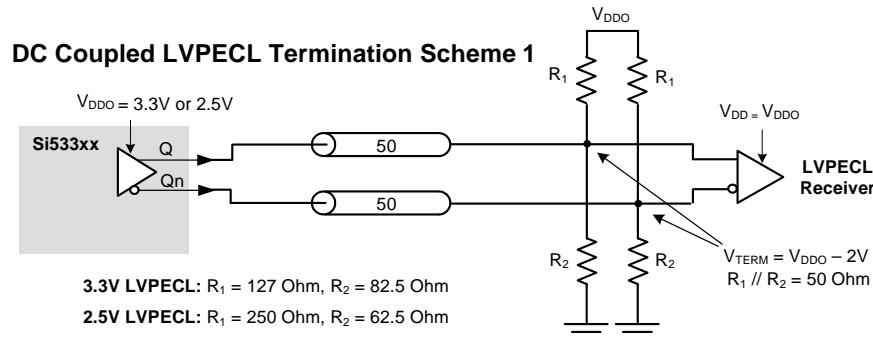
1. Output enable active high
2. On the next negative transition of CLK0 or CLK1.
3. Single-end: Q=low,  $\bar{Q}$ =high  
Differential: Q=low, Q=high

## 2.8. Power Supply ( $V_{DD}$ and $V_{DDOX}$ )

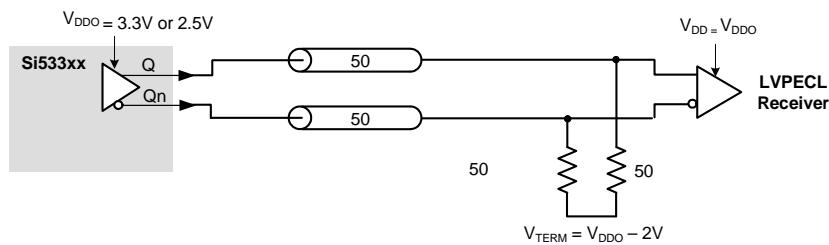
The device includes separate core ( $V_{DD}$ ) and output driver supplies ( $V_{DDOX}$ ). This feature allows the core to operate at a lower voltage than  $V_{DDO}$ , reducing current consumption in mixed supply applications. The core  $V_{DD}$  supports 3.3V, 2.5V, or 1.8V. Each output bank has its own  $V_{DDOX}$  supply, supporting 3.3V, 2.5V, or 1.8V.

## 2.9. Output Clock Termination Options

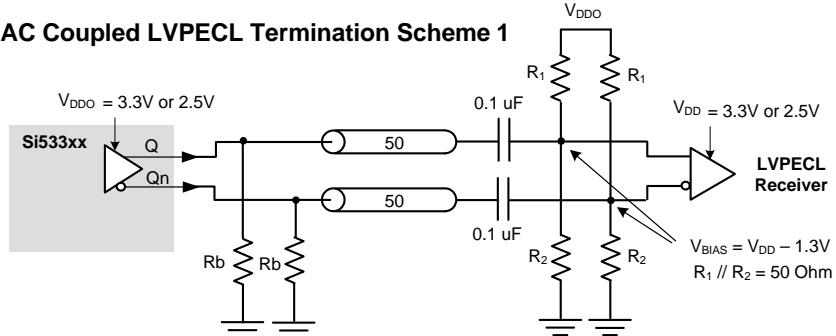
The recommended output clock termination options are shown below. Unused output clocks should be left floating.



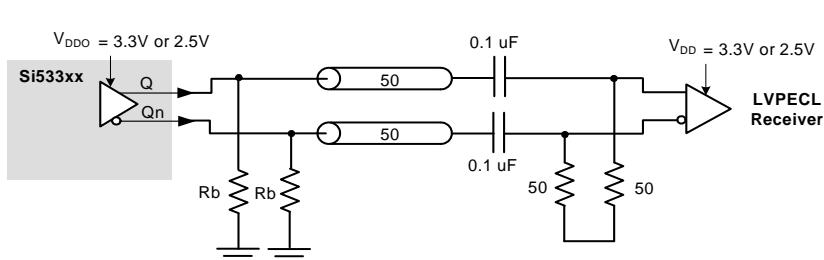
### DC Coupled LVPECL Termination Scheme 2



### AC Coupled LVPECL Termination Scheme 1

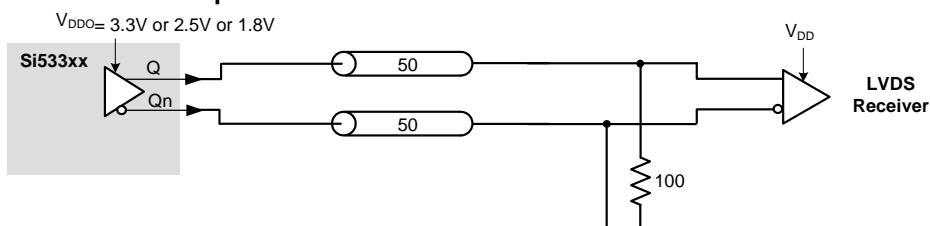


### AC Coupled LVPECL Termination Scheme 2

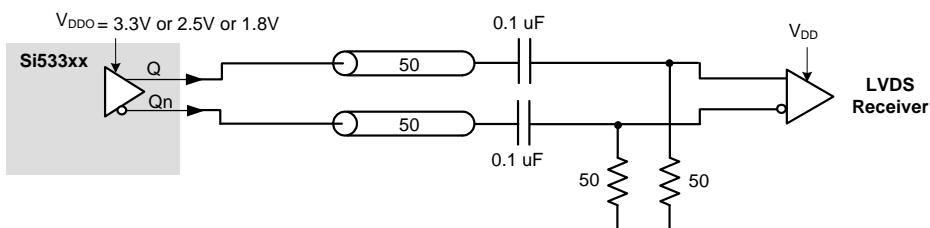


**Figure 7. LVPECL Output Termination**

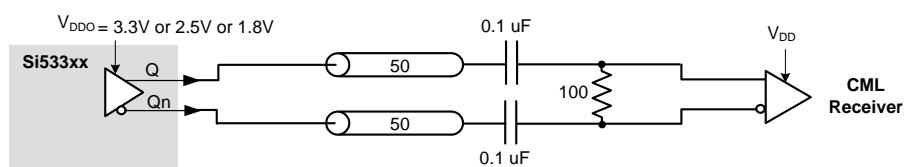
### DC Coupled LVDS and Low-Power LVPECL Termination



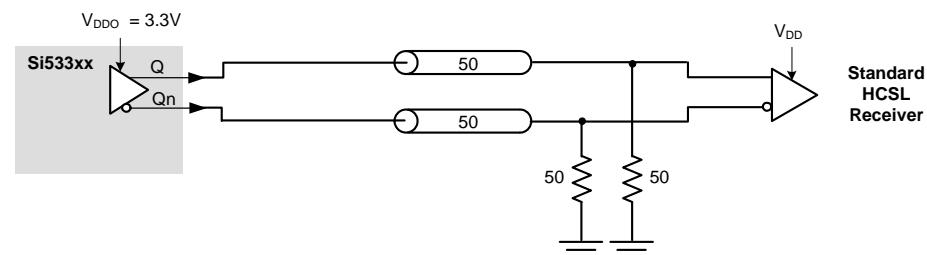
### AC Coupled LVDS Termination



### AC Coupled CML Termination



### DC Coupled HCSL Receiver Termination



### DC Coupled HCSL Source Termination

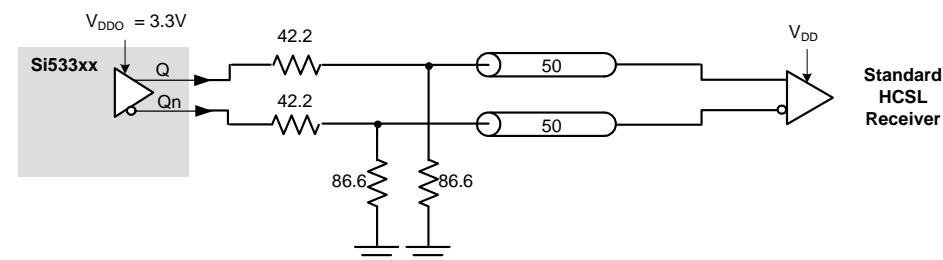


Figure 8. LVDS, CML, and HCSL Output Termination

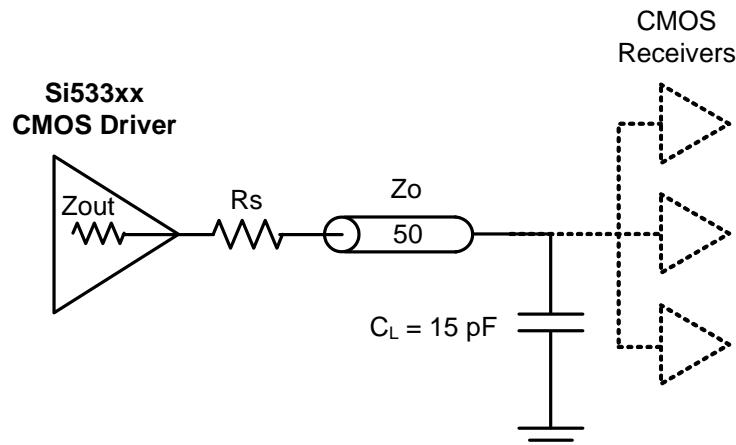


Figure 9. LVC MOS Output Termination

Table 17. Recommended LVC MOS  $R_s$  Series Termination

SFOUTX[1]	SFOUTX[0]	R <sub>s</sub> (ohms)		
		3.3 V	2.5 V	1.8 V
0	1	33	33	33
1	0	33	33	33
1	1	0	0	0
Open	0	0	0	0

## 2.10. AC Timing Waveforms

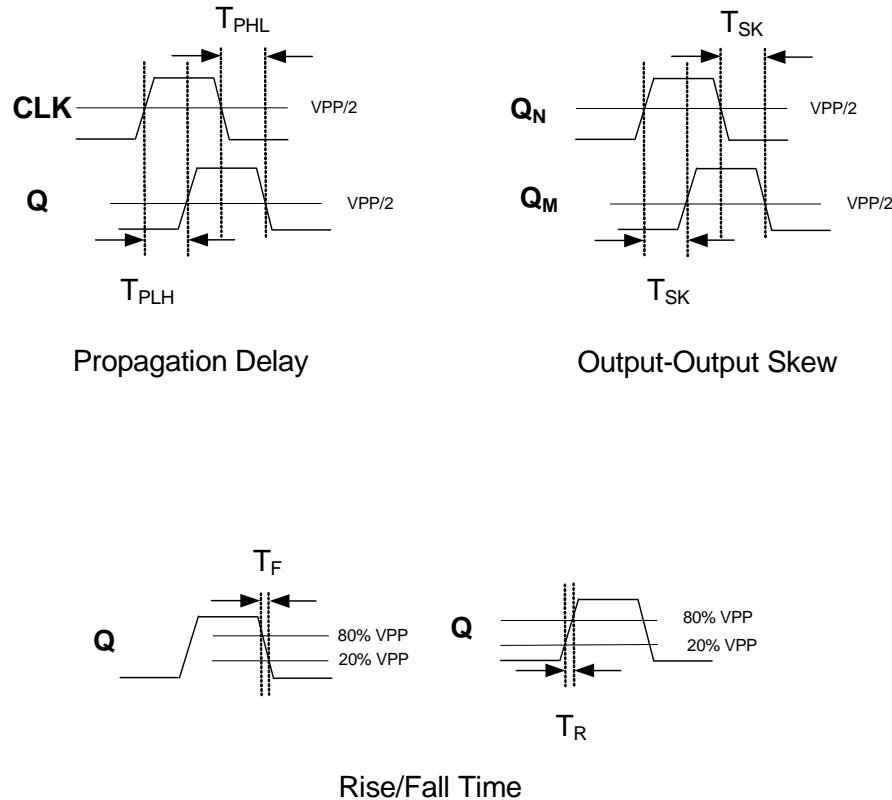
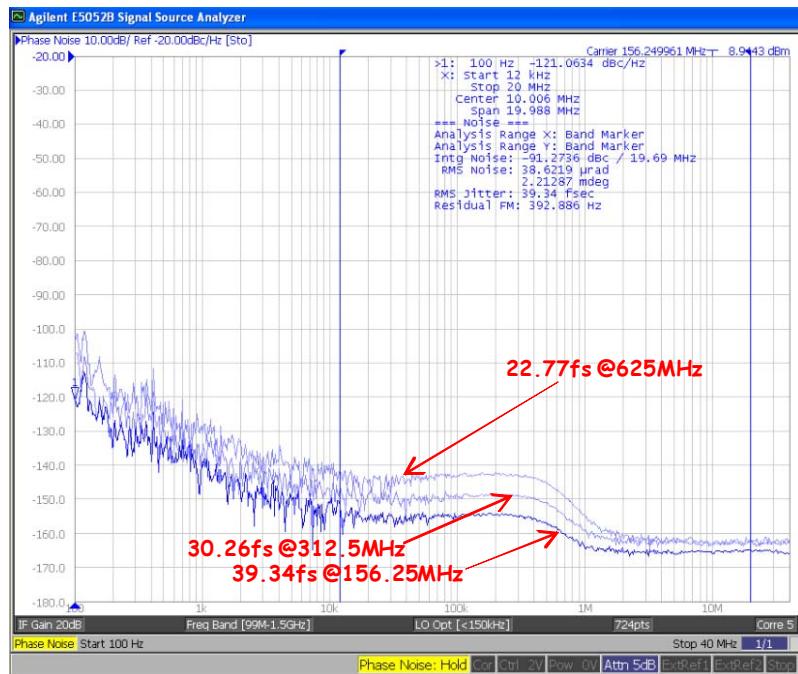
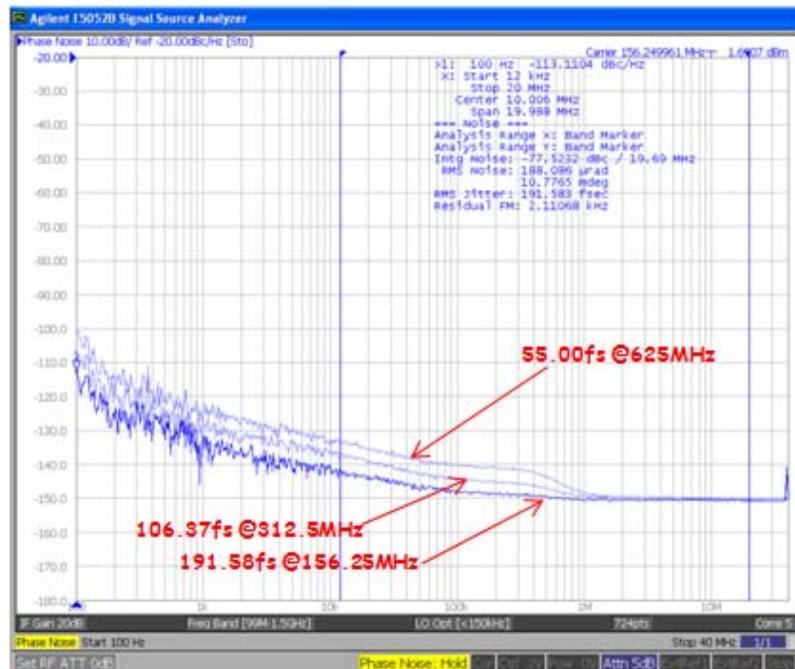


Figure 10. AC Waveforms

## 2.11. Typical Phase Noise Performance



**Source Jitter**



**Total Jitter**

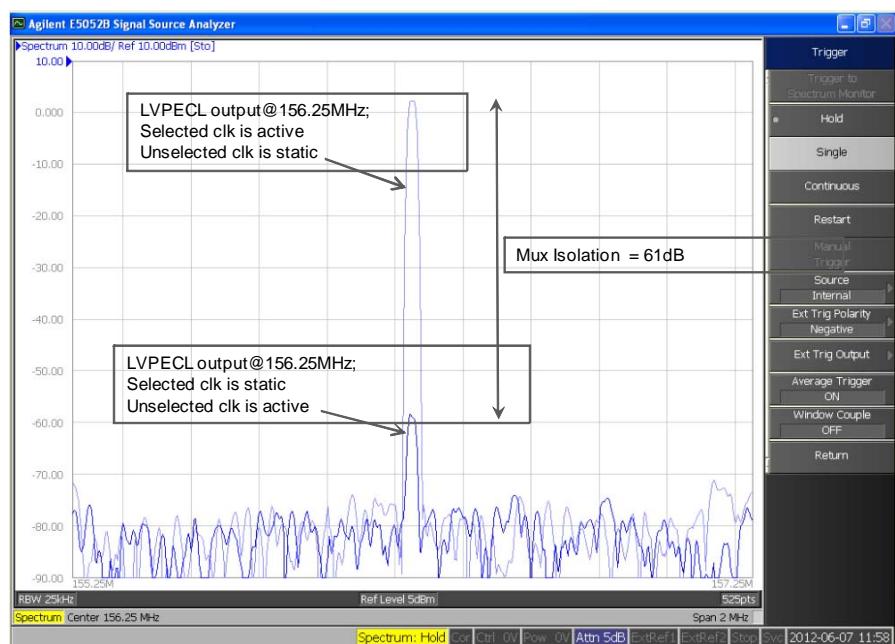
**Figure 11. Si53302 Phase Noise**

Note: Measured single-endedly.

**Table 18. Si53302 Additive Jitter**

Frequency (MHz)	Source Jitter (fs)	Total Jitter (fs)	Additive Jitter (fs)
156.25	39.34	191.58	187.50
312.5	30.26	106.37	101.98
625	22.77	55.00	50.07

## 2.12. Input Mux Noise Isolation



**Figure 12. Input Mux Noise Isolation**

## 2.13. Power Supply Noise Rejection

The device supports on-chip supply voltage regulation to reject noise present on the power supply, simplifying low jitter operation in real-world environments. This feature enables robust operation alongside FPGAs, ASICs and SoCs and may reduce board-level filtering requirements. For more information, see AN491: Power Supply Rejection for Low Jitter Clocks.

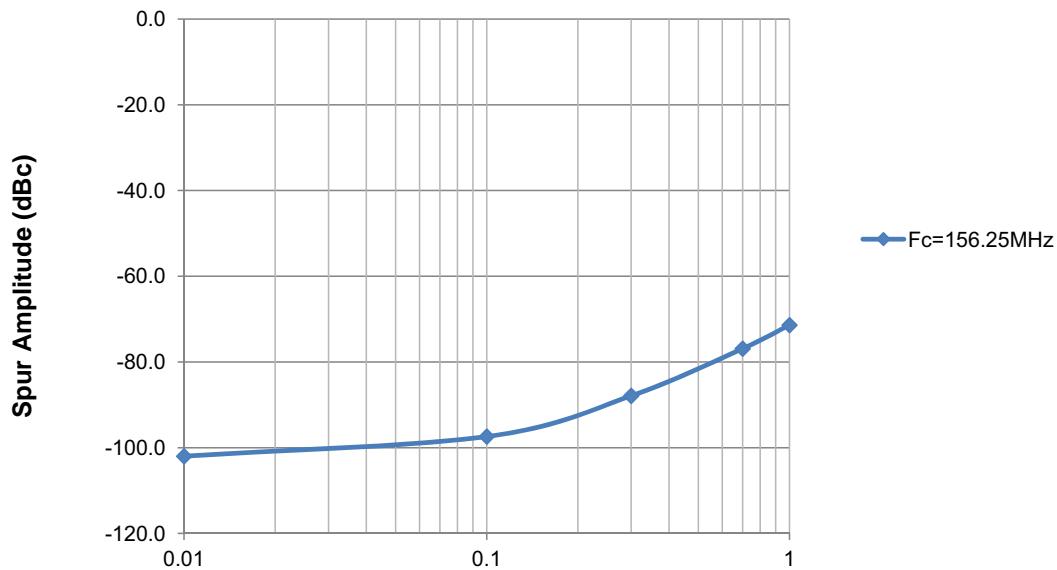
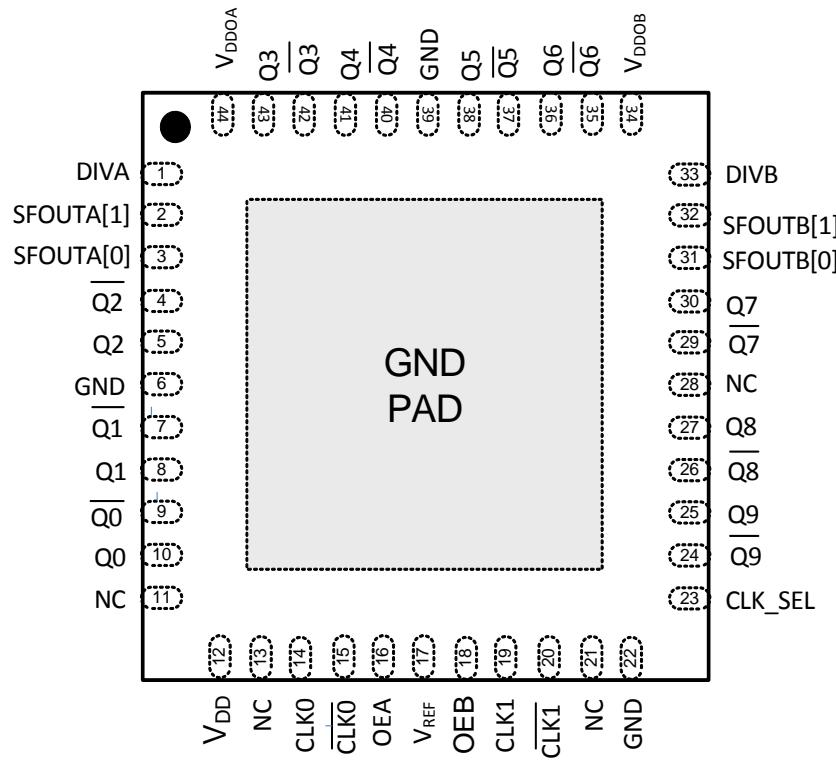


Figure 13. Power Supply Noise Rejection (100mVpp Sinusoidal Power Supply Noise Applied)

### 3. Pin Description: 44-Pin QFN



**Table 19. Si53302 44-Pin QFN Descriptions**

Pin #	Name	Description
1	DIVA	Output divider control pin for Bank A Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or V <sub>DD</sub> .
2	SFOUTA[1]	Output signal format control pin for Bank A Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or V <sub>DD</sub> .
3	SFOUTA[0]	Output signal format control pin for Bank A Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or V <sub>DD</sub> .
4	$\overline{Q2}$	Output clock 2 (complement)
5	Q2	Output clock 2
6	GND	Ground
7	$\overline{Q1}$	Output clock 1 (complement)
8	Q1	Output clock 1

Table 19. Si53302 44-Pin QFN Descriptions (Continued)

Pin #	Name	Description
9	$\overline{Q_0}$	Output clock 0 (complement)
10	$Q_0$	Output clock 0
11	NC	No connect
12	VDD	Core voltage supply Bypass with 1.0 $\mu\text{F}$ capacitor and place close to the VDD pin as possible
13	NC	No connect
14	CLK0	Input clock 0
15	$\overline{\text{CLK}0}$	Input clock 0 (complement) When CLK0 is driven by a single-end input, connect $V_{\text{REF}}$ to $\overline{\text{CLK}0}$ $\text{CLK}0$ contains an internal pull-up resistor
16	OEA	Output enable—Bank A When OE = high, the Bank A outputs are enabled When OE = low, Q is held low and $\overline{Q}$ is held high for differential formats For LVC MOS, both Q and $\overline{Q}$ are held low when OE is set low OEA contains an internal pull-up resistor
17	$V_{\text{REF}}$	Input reference voltage When driven by a LVC MOS clock input, connect the unused clock input to $V_{\text{REF}}$ and a 0.1 $\mu\text{F}$ cap to ground. When driven by a differential clock, do not connect the $V_{\text{REF}}$ pin.
18	OEB	Output enable—Bank B When OE = high, the Bank B outputs are enabled When OE = low, Q is held low and $\overline{Q}$ is held high for differential formats For LVC MOS, both Q and $\overline{Q}$ are held low when OE is set low OEB contains an internal pull-up resistor.
19	CLK1	Input clock 1
20	$\overline{\text{CLK}1}$	Input clock 1 (complement) When CLK1 is driven by a single-end input, connect $V_{\text{REF}}$ to $\overline{\text{CLK}1}$ $\text{CLK}1$ contains an internal pull-up resistor
21	NC	No connect
22	GND	Ground
23	CLK_SEL	MUX input select pin (LVC MOS) Clock inputs are switched without the introduction of glitches When CLK_SEL is high, CLK1 is selected When CLK_SEL is low, CLK0 is selected CLK_SEL contains an internal pull-down resistor
24	$\overline{Q_9}$	Output clock 9 (complement)
25	$Q_9$	Output clock 9
26	$\overline{Q_8}$	Output clock 8 (complement)

# Si53302

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**Table 19. Si53302 44-Pin QFN Descriptions (Continued)**

Pin #	Name	Description
27	Q8	Output clock 8
28	NC	No connect
29	$\overline{Q7}$	Output clock 7 (complement)
30	Q7	Output clock 7
31	SFOUTB[0]	Output signal format control pin for Bank B Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or $V_{DD}$ .
32	SFOUTB[1]	Output signal format control pin for Bank B Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or $V_{DD}$ .
33	DIVB	Output divider configuration bit for Bank B Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or $V_{DD}$ .
34	$V_{DDOB}$	Output Clock Voltage Supply—Bank B (Outputs: Q5 to Q9) Bypass with 1.0 $\mu$ F capacitor and place close to the $V_{DDOB}$ pin as possible
35	$\overline{Q6}$	Output clock 6 (complement)
36	Q6	Output clock 6
37	$\overline{Q5}$	Output clock 5 (complement)
38	Q5	Output clock 5.
39	GND	Ground.
40	$\overline{Q4}$	Output clock 4 (complement)
41	Q4	Output clock 4.
42	$\overline{Q3}$	Output clock 3 (complement)
43	Q3	Output clock 3
44	$V_{DDOA}$	Output Voltage Supply—Bank A (Outputs: Q0 to Q4) Bypass with 1.0 $\mu$ F capacitor and place close to the $V_{DDOA}$ pin as possible
GND Pad	GND	Ground Pad Power supply ground and thermal relief

#### 4. Ordering Guide

Part Number	Package	PB-Free, ROHS-6	Temperature
Si53302-B-GM	44-QFN	Yes	-40 to 85 °C

## 5. Package Outline

### 5.1. 7x7 mm 44-QFN Package Diagram

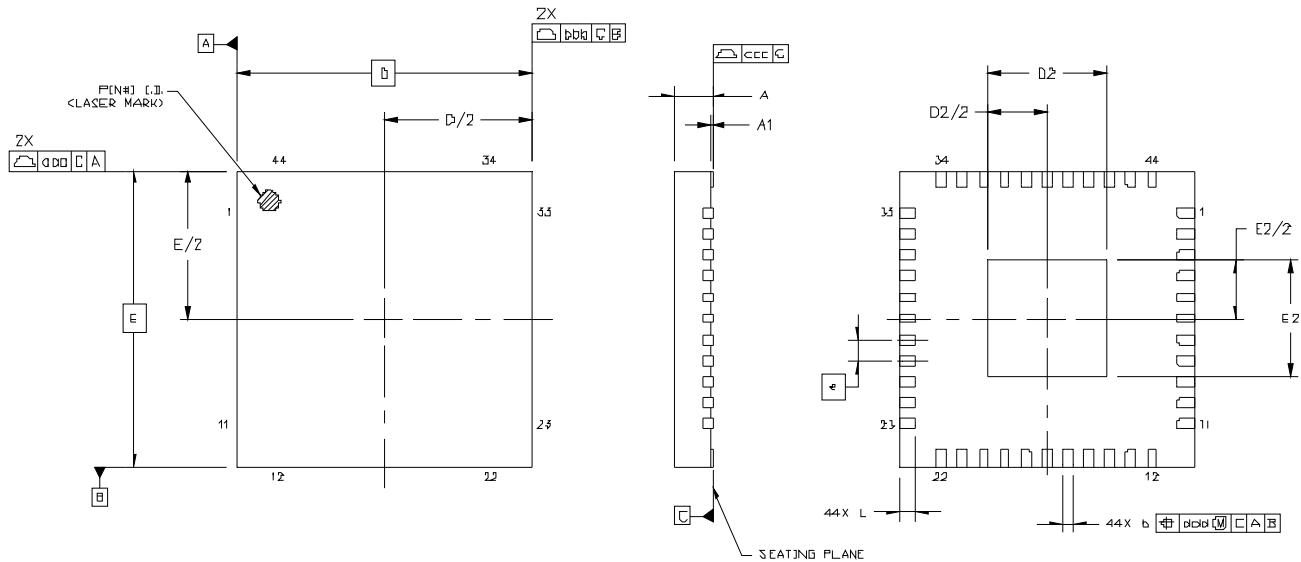


Figure 14. Si53302 7x7 mm 44-QFN Package Diagram

**Table 20. Package Diagram Dimensions**

<b>Dimension</b>	<b>MIN</b>	<b>NOM</b>	<b>MAX</b>
A	0.80	0.85	0.90
A1	0.00	0.02	0.05
b	0.18	0.25	0.30
D	7.00 BSC		
D2	2.65	2.80	2.95
e	0.50 BSC		
E	7.00 BSC		
E2	2.65	2.80	2.95
L	0.30	0.40	0.50
aaa	—	—	0.10
bbb	—	—	0.10
ccc	—	—	0.08
ddd	—	—	0.10
<b>Notes:</b>			
1. All dimensions shown are in millimeters (mm) unless otherwise noted.			
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.			
3. This drawing conforms to the JEDEC Solid State Outline MO-220.			
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.			

## 6. PCB Land Pattern

### 6.1. 7x7 mm 44-QFN Package Land Pattern

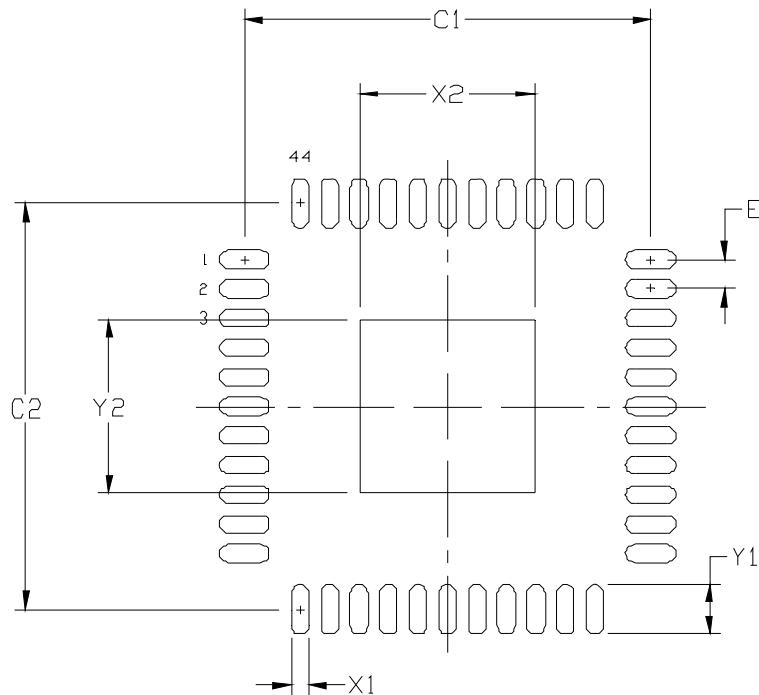


Figure 15. Si53302 7x7 mm 44-QFN Package Land Pattern

Table 21. PCB Land Pattern

Dimension	Min	Max
C1	6.80	6.90
C2	6.80	6.90
E	0.50 BSC	
X1	0.20	0.30

Dimension	Min	Max
X2	2.85	2.95
Y1	0.75	0.85
Y2	2.85	2.95

**Notes:**

**General**

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.

**Solder Mask Design**

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

**Stencil Design**

1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
2. The stencil thickness should be 0.125 mm (5 mils).
3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
4. A 2x2 array of 1.0 mm square openings on 1.45 mm pitch should be used for the center ground pad.

**Card Assembly**

1. A No-Clean, Type-3 solder paste is recommended.
2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

## 7. Top Marking

### 7.1. Si53302 Top Marking



### 7.2. Top Marking Explanation

<b>Mark Method:</b>	Laser	
<b>Font Size:</b>	1.9 Point (26 mils) Right-Justified	
<b>Line 1 Marking:</b>	Device Part Number	<b>53302-B-GM</b>
<b>Line 2 Marking:</b>	YY=Year WW=Work Week	Assigned by Assembly Supplier. Corresponds to the year and work week of the mold date.
	TTTTTT=Mfg Code	Manufacturing Code from the Assembly Purchase Order form.
<b>Line 3 Marking:</b>	Circle=1.3 mm Diameter Center-Justified	“e3” Pb-Free Symbol
	Country of Origin ISO Code Abbreviation	<b>TW</b>
<b>Line 4 Marking</b>	Circle = 0.75 mm Diameter Filled	Pin 1 Identification

## DOCUMENT CHANGE LIST

### Revision 0.1 to Revision 0.2

- Added termination resistors to Figure 3, “Differential DC-Coupled Input Terminations,” on page 11.

### Revision 0.2 to Revision 0.3

- Removed LOS.

### Revision 0.3 to 0.4

- Formatting changes.
- Updated part number to revision B.
- Added phase noise plot, PSRR figure, input mux isolation figure.
- Updated AC/DC specifications.

### Revision 0.4 to 0.41

- Formatting changes.
- Updated AC/DC specifications.

**NOTES:**

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